



Ultrahigh-Speed Switching Applications

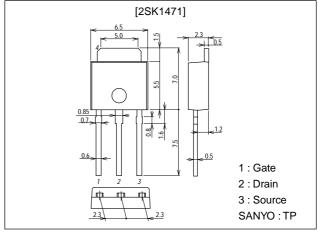
Features

- · Low ON resistance.
- · Ultrahigh-speed switching.
- · Low-voltage drive.

Package Dimensions

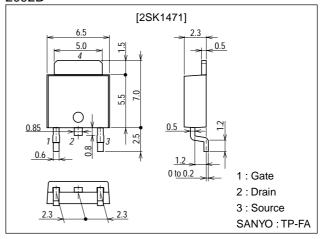
unit:mm

2083B



unit:mm

2092B



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Specifications

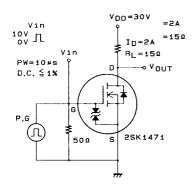
Absolute Maximum Ratings at Ta = 25°C

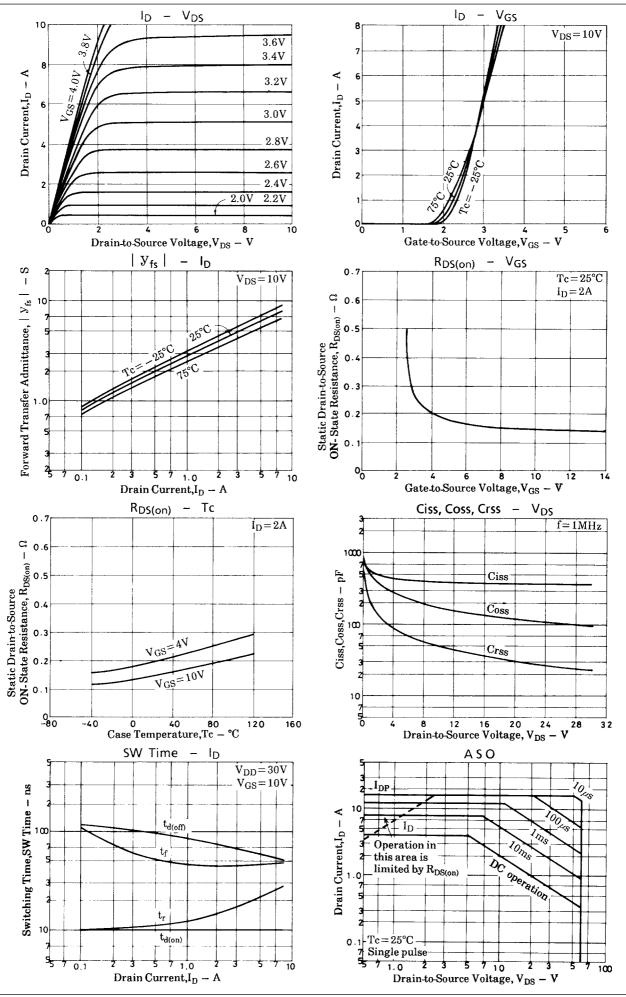
Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		60	V
Gate-to-Source Voltage	VGSS		±15	V
Drain Current (DC)	I _D		4	Α
Drain Current (pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	16	Α
Allowable Power Dissipation	PD		1.0	W
	ן יט	Tc=25°C	20	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

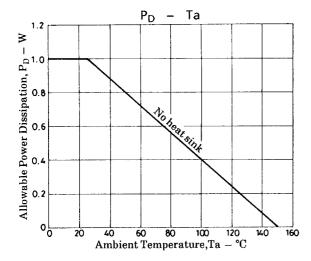
Electrical Characteristics at Ta = 25°C

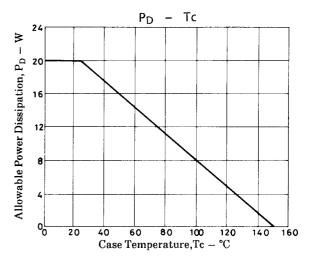
Parameter	Symbol	Conditions	Ratings			1.114
Parameter			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _{GS} =0	60			V
Gate-to-Source Breakdown Voltage	V(BR)GSS	IG=±100μA, V _{DS} =0	±15			V
Zero-Gate Votlage Drain Current	IDSS	V _{DS} =60V, V _{GS} =0			100	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±12V, V _{DS} =0			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	1.0		2.0	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =2A	2.5	4		S
Static Drain-to-Source On-State Resistance	R _{DS(on)} 1	I _D =2A, V _{GS} =10V		0.15	0.2	Ω
Static Drain-to-Source On-State Resistance	R _{DS(on)} 2	I _D =2A, V _{GS} =4V		0.2	0.27	Ω
Input Capacitance	Ciss	V _{DS} =20V, f=1MHz		380		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		120		pF
Reverse Transfer Capacitance	Crss	V _{DS} =20V, f=1MHz		30		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit		10		ns
Rise Time	t _r	See specified Test Circuit		15		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit		75		ns
Fall Time	t _f	See specified Test Circuit		45		ns
Diode Forward Voltage	V _{SD}	I _S =4A, V _{GS} =0		1.0	1.5	V

Switching Time Test Circuit









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